



**GreenPAK** ™

# 32PIN adapter #3



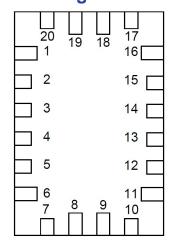
### **General Description**

Dialog SLG7RN45803 is a low power and small form device. The SoC is housed in a 2mm x 3mm STQFN package which is optimal for using with small devices.

### **Features**

- Low Power Consumption
- Pb Free / RoHS Compliant
- Halogen Free
- STQFN 20 Package

# **Pin Configuration**



STQFN-20 (Top view)

### Pin name

Pin #	Pin name	Pin#	Pin name
1	NC	11	
2	NC	12	
3	NC	13	
4	NC	14	
5	NC	15	
6	NC	16	
7	VDD	17	AGND
8		18	NC
9		19	NC
10	NC	20	GND



**Pin Configuration** 

Pin#	Pin Name	Туре	Pin Description	Internal Resistor
1	NC		Keep Floating or Connect to GND	
2	NC		Keep Floating or Connect to GND	
3	NC		Keep Floating or Connect to GND	
4	NC		Keep Floating or Connect to GND	
5	NC		Keep Floating or Connect to GND	
6	NC		Keep Floating or Connect to GND	
7	VDD	PWR	Supply Voltage	
8		Digital Input	Digital Input without Schmitt trigger	floating
9		Digital Input	Digital Input without Schmitt trigger	floating
10	NC		Keep Floating or Connect to GND	
11		Analog Output	LDO0 VOUT Analog Output	floating
12		Analog Input	LDO0/1 VIN Analog Input	floating
13		Analog Output	LDO1 VOUT Analog Output	floating
14		Analog Output	LDO2 VOUT Analog Output	floating
15		Analog Input	LDO2/3 VIN Analog Input	floating
16		Analog Output	LDO3 VOUT Analog Output	floating
17	AGND	AGND	Ground	
18	NC		Keep Floating or Connect to GND	
19	NC		Keep Floating or Connect to GND	
20	GND	GND	Ground	

**Ordering Information** 

Part Number	Package Type
SLG7RN45803V	20-pin STQFN
SLG7RN45803VTR	20-pin STQFN - Tape and Reel (3k units)



### **Absolute Maximum Conditions**

Parameter	Min.	Max.	Unit
Supply Voltage on VDD relative to GND	-0.3	7	V
DC Input Voltage	GND - 0.5V	VDD + 0.5V	V
Current at Input Pin	-1.0	1.0	mA
Input leakage (Absolute Value)		1000	nA
Storage Temperature Range	-65	150	°C
Junction Temperature		150	°C
ESD Protection (Human Body Model)	2000		V
ESD Protection (Charged Device Model)	1300		V
Moisture Sensitivity Level		1	

# **Electrical Characteristics**

Symbol	Parameter Condition/Note		Min.	Тур.	Max.	Unit
$V_{DD}$	Supply Voltage		2.3	3.3	5.5	٧
TA	Operating Temperature		-40	25	85	°C
C <sub>VDD</sub>	Capacitor Value at VDD			0.1		μF
Cin	Input Capacitance			4		рF
lα	Quiescent Current	Static inputs and floating outputs		1		μA
Vo	Maximal Voltage Applied to any PIN in High-Impedance State				VDD+0.3	V
	Maximum Average or DC	T <sub>J</sub> = 85°C			73	mA
$I_{VDD}$	Current Through VDD Pin (Per chip side, see Note 2)	T <sub>J</sub> = 110°C			35	mA
	Maximum Average or DC	T <sub>J</sub> = 85°C			152	mΑ
IGND	Current Through GND Pin (Per chip side, see Note 2)	T <sub>J</sub> = 110°C			72	mA
		Logic Input at VDD=2.5V	0.7xVDD		VDD+0.3	V
Vін	HIGH-Level Input Voltage	Logic Input at VDD=3.3V	0.7xVDD		VDD+0.3	V
		Logic Input at VDD=5.0V	0.7xVDD		VDD+0.3	V
	LOW-Level Input Voltage	Logic Input at VDD=2.5V	GND-0.3		0.3xVDD	V
VIL		Logic Input at VDD=3.3V	GND-0.3		0.3xVDD	<b>V</b>
		Logic Input at VDD=5.0V	GND-0.3		0.3xVDD	V
LDO0	LDO0 output voltage	Vout0 voltage		2.00		V
LDOU	LDO0 output voltage	Vout1 voltage		2.00		V
LDO1	LDO1 output voltage	Vout0 voltage		0.90		V
LDOT	LDO i output voltage	Vout1 voltage		0.90		V
LDO2	LDO2 output voltage	Vout0 voltage		0.90		V
LDOZ	LDO2 output voltage	Vout1 voltage		0.90		V
LDO3	LDO3 output voltage	Vout0 voltage		0.90		V
LD03	LDO3 output voltage	Vout1 voltage		0.90		V
Tsu	Startup Time	From VDD rising past PON <sub>THR</sub>		1.3		ms
PON <sub>THR</sub>	Power On Threshold	V <sub>DD</sub> Level Required to Start Up the Chip	1.34	1.55	1.74	V
POFFTHR	Power Off Threshold	V <sub>DD</sub> Level Required to Switch Off the Chip	1.05	1.25	1.45	V
Note:						



- 1. DC or average current through any pin should not exceed value given in Absolute Maximum Conditions.
- 2. The GreenPAK's power rails are divided in two sides. PINs 1, 2, 3, 4, 5 and 6 are connected to one side, PINs 8, 9, 10, 18 and 19 to another.
- 3. Guaranteed by Design.

### I<sup>2</sup>C Specifications

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
FscL	Clock Frequency, SCL	$V_{DD} = (2.35.5) V$			400	kHz
t <sub>LOW</sub>	Clock Pulse Width Low	$V_{DD} = (2.35.5) V$	1300			ns
tніgн	Clock Pulse Width High	$V_{DD} = (2.35.5) V$	600			ns
	Input Filter Spike	$V_{DD} = 2.5V \pm 8\%$			168	ns
tı	Suppression (SCL, SDA)	$V_{DD} = 3.3V \pm 10\%$			157	ns
	Suppression (SCL, SDA)	$V_{DD} = 5.0V \pm 10\%$			156	ns
taa	Clock Low to Data Out Valid	$V_{DD} = (2.35.5) V$			900	ns
t <sub>BUF</sub>	Bus Free Time between Stop and Start	V <sub>DD</sub> = (2.35.5) V	1300			ns
t <sub>HD_STA</sub>	Start Hold Time	$V_{DD} = (2.35.5) V$	600			ns
t <sub>SU_STA</sub>	Start Set-up Time	$V_{DD} = (2.35.5) V$	600			ns
t <sub>HD_DAT</sub>	Data Hold Time	$V_{DD} = (2.35.5) V$	0			ns
t <sub>SU_DAT</sub>	Data Set-up Time	$V_{DD} = (2.35.5) V$	100			ns
t <sub>R</sub>	Inputs Rise Time	$V_{DD} = (2.35.5) V$			300	ns
t <sub>F</sub>	Inputs Fall Time	$V_{DD} = (2.35.5) V$			300	ns
t <sub>su_sto</sub>	Stop Set-up Time	$V_{DD} = (2.35.5) V$	600			ns
t <sub>DH</sub>	Data Out Hold Time	$V_{DD} = (2.35.5) V$	50			ns

## **LDO Regulator Thermal Limitations**

Symbol	Parameter Condition/Note		Min.	Тур.	Max.	Unit
		85 °C ambient, Total IC package			0.6	W
ICTL	Thermal Limitation	70 °C ambient, Total IC package			0.8	W
		Max Watt per LDO <sup>1</sup>			0.5	W
Chutdown	Thermal Shutdown <sup>2</sup>		115	125	135	°C
Shutdown	Thermal Shutdown Recovery		90	100	110	°C

#### Note:

# **LDO HP MODE Electrical Specifications**

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
Іоит	Output Current Rating				150	mA
V <sub>IN</sub>	Voltage Input		2.3		VDD	V
$V_{DO}$	Voltage Dropout			250	300	mV
ΔVουτ	Output Voltage Accuracy	over PVT of V <sub>OUT</sub> > 1.5 V	-3		+3	%
Δνουι	(see Note 1)	over PVT of V <sub>OUT</sub> ≤ 1.5 V	-60		+60	mV
en	Noise Voltage (rms)	10 Hz to 100 kHz		75		μV

<sup>1.</sup> Please note that Max Watt LDO multiplied by number of LDOs can easily exceed the Max Watt for the total IC package. In this case an external resistor should be used on LDO Vin to lower the voltage drop across the LDO Regulator.

<sup>2.</sup> Lower Thermal shutdown levels may be achieved by using the temperature sensor and comparator.



PSRR	Power Supply Rejection Ratio (see Note 2)	100 Hz to 100 kHz	TBD	50		dB
CTRR	Crosstalk Rejection Ratio	LDO0 to LDO1 regulation perturbation, and LDO2 to LDO3 perturbation at 0 to 150 mA at 1 kHz at 1.8 V Vout	TBD	50		dB
$\Delta V_{LINE}$	Line Regulation	$V_{OUT} + 0.5 V < V_{IN} \le 5.5 V$	-1%		+1%	%/V
$\Delta V_{LOAD}$	Load Regulation	1 mA < I <sub>OUT</sub> < 150 mA			0.3	mV/ mA
ΔV <sub>TC</sub>	V <sub>OUT</sub> Temp Coefficient			100		ppm/ C
Cin	External Input Capacitor (see Note 2)		2			μF
Соит	External Output Capacitor		2			μF
tss_0	Soft Start Option 0 Time	V <sub>ОUТ</sub> 5% to 95%	-20%	10	+20%	V/ms
tss_1	Soft Start Option 1 Time	V <sub>ОUТ</sub> 5% to 95%	-20%	20	+20%	V/ms
tss_2	Soft Start Option 2 Time	V <sub>ОUТ</sub> 5% to 95%	-30%	1.25	+30%	V/ms
tss_3	Soft Start Option 3 Time	V <sub>ОUТ</sub> 5% to 95%	-30%	2.50	+30%	V/ms
SC	Short Circuit Protection		TBD	TBD	TBD	mA
twait	Wait Time	Time from EN=1 to V <sub>OUT</sub> start rise		500		μs
R₀	Output Discharge Pull-down Resistance	EN=0, Dis_EN = 1		300		Ω

#### Note:

**LDO LP MODE Electrical Specifications** 

Symbol	Parameter	Condition/Note	Min.	Тур.	Max.	Unit
l <sub>out</sub>	Output Current Rating				100	μA
V <sub>IN</sub>	Voltage Input		2.3		VDD	V
$V_{DO}$	Voltage Dropout			500	750	mV
$\Delta V_{OUT}$	Output Voltage Accuracy	over PVT	-10		+10	%
Cin	External Input Capacitor (see Note 1)		2			μF
Соит	External Output Capacitor (see Note 1)		2			μF
$R_D$	Output Discharge Pull-down Resistance	EN=0, Dis_EN = 1		300		Ω

Note:

1. X7R-type and X5R-type capacitors are recommended

**Chip address** 

HEX	BIN	DEC
0x28	0101000	40



<sup>1.</sup> Accuracy specifies all the effects of line regulation ( $\Delta V_{LINE}$ ), load regulation ( $\Delta V_{LOAD}$ ), and temperature coefficient ( $\Delta V_{TC}$ ),

<sup>2.</sup> X7R-type and X5R-type capacitors are recommended



### **I2C Description**

#### 1. I2C Basic Command Structure

Each command to the I2C Serial Communications block begins with a Control Byte. The bits inside this Control Byte are shown in Figure 1. After the Start bit, the first four bits are a control code, which can be set by the user in reg<1867:1864>. The Block Address is the next three bits (A10, A9, A8), which will define the most significant bits in the addressing of the data to be read ("1") or written ("0") by the command. This Control Byte will be followed by an Acknowledge bit (ACK).

With the exception of the Current Address Read command, all commands will have the Control Byte followed by the Word Address. The Word Address, in conjunction with the three address bits in the Control Byte, will define the specific data byte to be read or written in the command. Figure 1 shows this basic command structure.

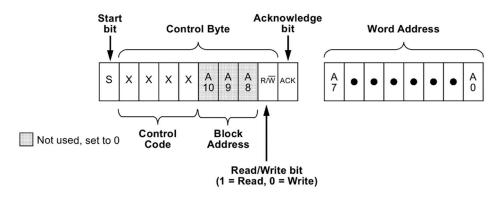


Figure 1. I2C Basic Command Structure

### 2. I2C Serial General Timing

Shown in Figure 2 is the general timing characteristics for the I2C Serial Communications block.

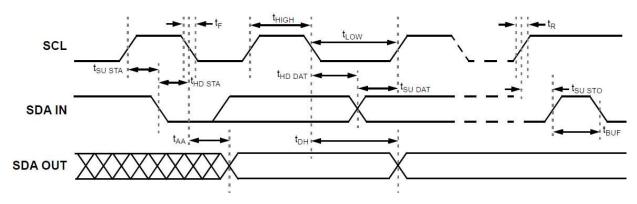


Figure 2. I2C Serial General Timing



#### 3. I2C Serial Communications: Read and Write Commands

Following the Start condition from the master, the Control Code [4 bits], the block address [3 bits] and the R/W bit (set to "0"), is placed onto the bus by the Bus Master. After the I2C Serial Communications block has provided an Acknowledge bit (ACK) the next byte transmitted by the master is the Word Address. The Block Address is the next three bits, and is the higher order addressing bits (A10, A9, A8), which when added to the Word Address will together set the internal address pointer in the SLG7RN45803 to the correct data byte to be written. After the SLG7RN45803 sends another Acknowledge bit, the Bus Master will transmit the data byte to be written into the addressed memory location. The SLG7RN45803 again provides an Acknowledge bit and then the Bus Master generates a Stop condition. The internal write cycle for the data will take place at the time that the SLG7RN45803 generates the Acknowledge bit.

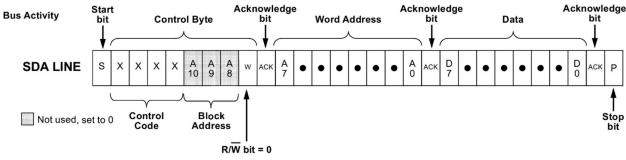


Figure 3. I2C Write Command

The Random Read command starts with a Control Byte (with  $R/\overline{W}$  bit set to "0", indicating a write command) and Word Address to set the internal byte address, followed by a Start bit, and then the Control Byte for the read (exactly the same as the Byte Write command). The Start bit in the middle of the command will halt the decoding of a Write command, but will set the internal address counter in preparation for the second half of the command. After the Start bit, the Bus Master issues a second control byte with the  $R/\overline{W}$  bit set to "1", after which the SLG7RN45803 issues an Acknowledge bit, followed by the requested eight data bits.

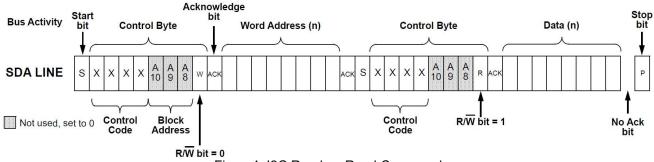


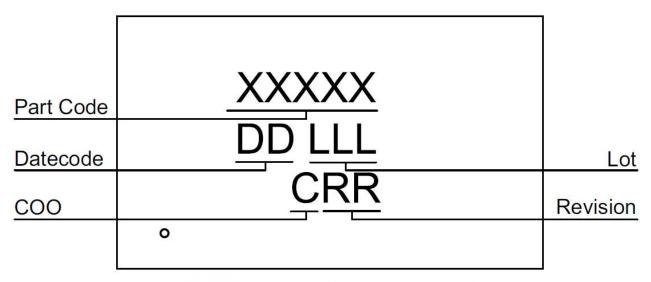
Figure 4. I2C Random Read Command

4. I2C register control data

Address Byte	Register Bit	Block	Function
0xF4	reg<1952>	Virtual Input <0>	Enable (0) and disable (1) switch0 (VOUT0) Default is 0.
UXF4	reg<1953>	Virtual Input <1>	Enable (0) and disable (1) switch1 (VOUT1) Default is 0.
0xC0	reg<1543:1536>	CNT0 Control Data	PWM control data for LED1 Default is 0x65. Duty cycle is 0%.
0xC1	reg<1551:1544>	CNT1 Control Data	PWM control data for LED2 Default is 0x65. Duty cycle is 0%.
0xC2	reg<1559:1552>	CNT2 Control Data	PWM control data for LED3 Default is 0x65. Duty cycle is 0%.



# **Package Top Marking**



XXXXX - Part ID Field: identifies the specific device configuration

DD - Date Code Field: Coded date of manufacture

LLL - Lot Code: Designates Lot #

C - Assembly Site/COO: Specifies Assembly Site/Country of Origin

RR - Revision Code: Device Revision

Datasheet Revision	Programming Code Number	Lock Status	Checksum	Part Code	Part Code Revision	
0.10	001	U	0x5B58769C			06/01/2022

Lock coverage for this part is indicated by  $\sqrt{\ }$ , from one of the following options:

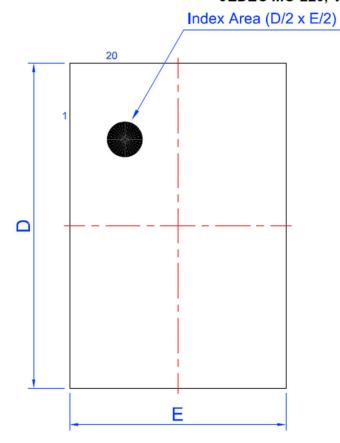
 Unlocked							
Locked for read, bits <1535:0>							
Locked for write, bits <1535:0>							
Locked for write all bits							
Locked for read and write bits <1535:0>							
Locked for read bits <1535:0> and write of all bits							

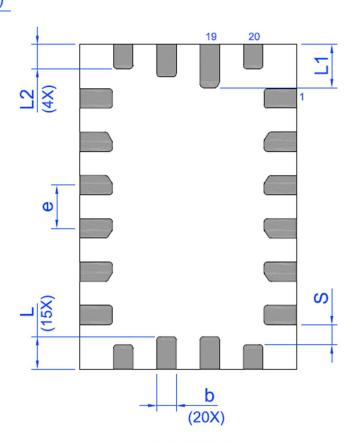
The IC security bit is locked/set for code security for production unless otherwise specified. The Programming Code Number is not changed based on the choice of locked vs. unlocked status.



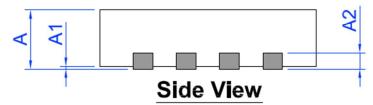
# **Package Drawing and Dimensions**

## STQFN 20L 2x3mm 0.4P FCD Package JEDEC MO-220, Variation WECE





# **Marking View**



**BTM View** 

# Unit: mm

Symbol	Min	Nom.	Max	Symbol	Min	Nom.	Max
Α	0.50	0.55	0.60	D	2.95	3.00	3.05
A1	0.005	-	0.050	Е	1.95	2.00	2.05
A2	0.10	0.15	0.20	L	0.25	0.30	0.35
b	0.13	0.18	0.23	L1	0.35	0.40	0.45
е	(	0.40 BSC		L2	0.175	0.225	0.275
S	0.185 TYP						

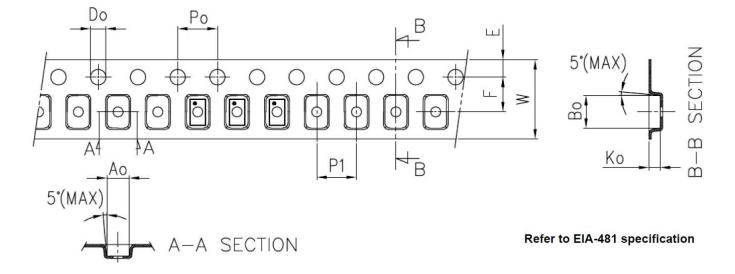


**Tape and Reel Specification** 

	- 1	Nominal	Max Units			Leader (min)		Trailer (min)		Таре	Part
Package Type		Package Size [mm]	per Reel	per Box	Reel & Hub Size [mm]	Pockets	Length [mm]	Pockets	Length [mm]	Width [mm]	Pitch [mm]
STQFN 20L 2x3mm 0.4P FCD	20	2 x 3 x 0.55	3000	3000	178/60	100	400	100	400	8	4

**Carrier Tape Drawing and Dimensions** 

Package Type	Pocket BTM Length	Pocket BTM Width	Pocket Depth	Index Hole Pitch	Pocket Pitch	Index Hole Diameter	Index Hole to Tape Edge	Index Hole to Pocket Center	Tape Width
	Α0	В0	K0	P0	P1	D0	E	F	W
STQFN 20L 2x3mm 0.4P FCD	2.2	3.15	0.76	4	4	1.5	1.75	3.5	8



# **Recommended Reflow Soldering Profile**

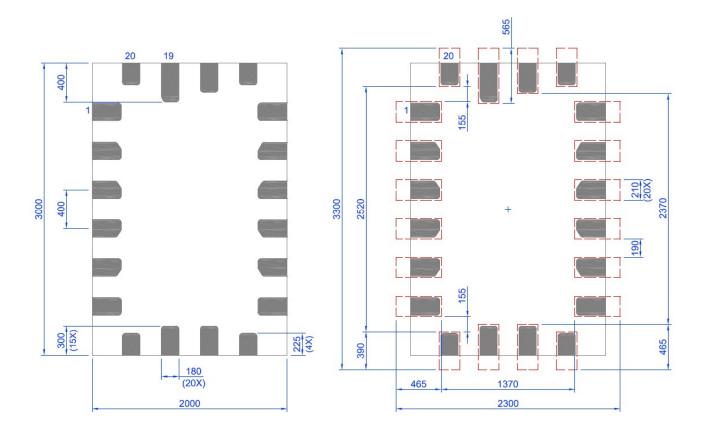
Please see IPC/JEDEC J-STD-020: latest revision for reflow profile based on package volume of 3.30 mm³ (nominal). More information can be found at <a href="https://www.jedec.org">www.jedec.org</a>.



### **Recommended Land Pattern**

Exposed Pad (PKG face down)

Recommended Land Pattern (PKG face down)



Unit:um





**Datasheet Revision History** 

Date	Version	Change
06/01/2022	0.10	New design for SLG46580 chip

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